




# Electrodeposition of Bi<sub>2</sub>Te<sub>3</sub> thin films for thermoelectric applications: effect of electrolyte pH

Vinod S. Khairnar<sup>1,\*</sup> , Anil N. Kulkarni<sup>2</sup>, Vishal V. Lonikar<sup>3</sup>, Anil B. Gite<sup>4</sup>, Mirtunjay Kumar<sup>5</sup>, Dipak P. Patil<sup>6</sup>, and Deepak P. Kadam<sup>1</sup>

<sup>1</sup>Department of Engineering Sciences, METs Institute of Engineering, MET Bhujbal Knowledge City, Nashik, India

<sup>2</sup>Department of Physics, NTVS's Patil Arts, Science and Commerce College, Nandurbar, India

<sup>3</sup>Department of Physics, Bhujbal Academy of Science and commerce, MET Bhujbal Knowledge City, Nashik, India

<sup>4</sup>Department of Physics, SNJB's Arts and Science College, Nashik, India

<sup>5</sup>Department of Materials, University of Manchester, Manchester, UK

<sup>6</sup>Department of Electronics and Telecommunication, Sandip Institute of Engineering and Management, Nashik, India

Received: 9 January 2023

Accepted: 19 March 2023

© The Author(s), under exclusive licence to Springer Science+Business Media, LLC, part of Springer Nature 2023

## ABSTRACT

Modern materials like Bi<sub>2</sub>Te<sub>3</sub> nanostructures are one of the most promising thermoelectric materials since they show a high value of the thermoelectric figure of merit. This paper reports the effect of electrolyte pH (in a low pH range starting from 0.25 to 1.50) on the structural, electrochemical, and thermoelectric properties of the electrodeposited Bi<sub>2</sub>Te<sub>3</sub> films. Two of the samples showed significantly high values of Seebeck coefficient (49.28 μV/T and 45.26 μV/T, respectively), which are comparable to the Si (42 μV/T), SiC nanowires (40 μV/T), and Ge (47 μV/T) thermoelectric materials. Also, the observed crystallinity and electrochemical behavior are in agreement with the thermoelectric results for electrodeposited Bi<sub>2</sub>Te<sub>3</sub> films. In nutshell, a lower range of pH of electrolytes has been found to be a significant control parameter in the present study. Such Plausible tailoring of properties would be helpful for the systematic study of complex and multi-composite materials for various applications.

## 1 Introduction

There are many thermoelectric materials being studied in the form of thin films. Materials like Bismuth Chalcogenides [1], Lead tellurides [2, 3], Inorganic Clathrates [4, 5], Mg-B<sup>IV</sup> compounds [6, 7], Homologous oxides [8, 9], Half-Heusler alloys [10, 11] etc.

Among these materials, in the current thread of research, Bi<sub>2</sub>Te<sub>3</sub> has been studied extensively. This is

due to its high value of thermoelectric figure of merit at room temperature. In addition, out of many methods of synthesis, electrodeposition method has been explored by the researchers. Electrodeposited Bi<sub>2</sub>Te<sub>3</sub> nanowire arrays (12–33 μV/K), pulse electrodeposited Bi<sub>2</sub>Te<sub>3</sub> thin films (– 65 μV/K), and *n*-type Bi<sub>2</sub>Te<sub>3</sub> films (– 51.6 μV/K) had shown Seebeck coefficient ranging from 12 to 65 μV/K [12–14].

Address correspondence to E-mail: vinodk\_ioe@bkc.met.edu